## NSN 5961-00-509-5678

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Inclosure Material:

Metal

**Overall Length:** 

0.295 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

**Mounting Method:** 

Threaded stud

**Features Provided:** 

Hermetically sealed case

**Overall Width Across Flats:** 

0.440 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

550.0 collector to base voltage, dc and 510.0 collector to emitter voltage, dc and 7.0 emitter to base voltage, dc

**Current Rating Per Characteristic:** 

1.00 amperes source cutoff current

Power Rating Per Characteristic:

15.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

**Special Features:** 

Junction pattern arrangement: npn

**Precious Material And Location:** 

Terminal surface gold

**Precious Material:** 

Gold

**Thread Series Designator:** 

Unf

**Terminal Type And Quantity:** 

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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